

TECHNICAL DATA DATA SHEET 4011, REV -

HERMETIC POWER MOSFET N-CHANNEL

FEATURES:

- 500 Volt, 0.85, Ohm, 5.5Amp MOSFET
- Isolated
- Hermetically Sealed

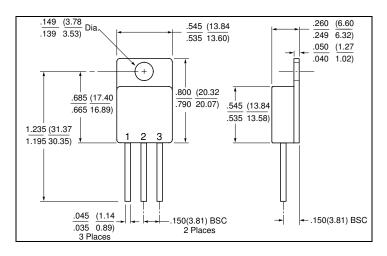
MAXIMUM RATINGS ALL RATINGS ARE AT T. = 25°C UNLESS OTHERWISE SPECIFIED. RATING SYMBOL MIN. TYP. MAX. UNITS GATE TO SOURCE VOLTAGE V_{GS} ±20 Volts --CONTINUOUS DRAIN CURRENT $T_{\rm C} = 25^{\circ}{\rm C}$ I_{D} -_ 5.5 Amps 22 PULSED DRAIN CURRENT $@ T_{C} = 25^{\circ}C$ -Amps I_{DM} -**OPERATING AND STORAGE TEMPERATURE** -55 T_{OP}/T_{STG} _ +150°C TERMAL RESISTANCE JUNCTION TO CASE 0.74 °C/W $R_{\theta JC}$ -- P_{D} 150 Watts TOTAL DEVICE DISSIPATION @ T_C = 25°C --

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS
DRAIN TO SOURCE BREAKDOWN VOLTAGE	BV _{DSS}	500	-	-	Volts
$V_{GS} = 0V, I_D = 1.0mA$					
DRAIN TO SOURCE ON STATE RESISTANCE		-	-		Ω
$V_{GS} = 10V, I_D = 3.5A$	R _{DS(ON)}			0.85	
GATE THRESHOLD VOLTAGE $V_{DS} = V_{GS}$, $I_D = 250 \mu A$	V _{GS(th)}	2.0	-	4.0	Volts
FORWARD TRANSCONDUCTANCE	g _{fs}	4.7	-	-	S(1/Ω)
$V_{DS} \ge 15V, \ I_D = 3.5A$					
ZERO GATE VOLTAGE DRAIN CURRENT, $T_J = 25^{\circ}C$	I _{DSS}	-	-	25	
$(V_{DS} = 0.8 \text{ x Max}. \text{ Rating}, V_{GS} = 0 \text{V}), T_{J} = 125^{\circ}\text{C}$				250	μA
GATE TO SOURCE LEAKAGE FORWARD $V_{GS} = 20V$	I _{GSS}	-	-	100	nA
GATE TO SOURCE LEAKAGE REVERSE V _{GS} = -20V				-100	
TOTAL GATE CHARGE $V_{GS} = 10V$,	Qg	-	-	68.5	
GATE TO SOURCE CHARGE $V_{DS} = 250V$,	Q _{gs}			12.5	nC
GATE TO DRAIN CHARGE $I_D = 5.5A$	Q _{gd}			40.5	
TURN ON DELAY TIME $V_{DD} = 250V$,	t _{d(ON)}	-	21	-	
RISE TIME $I_D = 5.5A$,	t _r		73		nsec
TURN OFF DELAY TIME $R_G = 9.1\Omega$,	t _{d(OFF)}		72		
FALL TIME $V_{GS} = 10V$	t _f		51		
CONTIUOUS SOURCE CURRENT	I _S	-	5.5	-	Amps
DIODE FORWARD VOLTAGE $T_J = 25^{\circ}C, I_S = 5.5V$	V _{SD}	-	-	1.5	Volts
$V_{GS} = 0V$					
REVERSE RECOVERY TIME $T_J = 25^{\circ}C$,	t _{rr}	-	-	700	nsec
I _S = 5.5A,					
di/dt ≤ = -100A/µsec,					
REVERSE RECOVERY CHARGE $V_{DD} \le 50V$	Q _{rr}			8.9	μC
INPUT CAPACITANCE $V_{GS} = 0V, V_{DS} = 25V,$	C _{iss}	-	1300	-	
OUTPUT CAPACITANCE f = 1.0MHz	C _{oss}		310		pF
REVERSE TRANSFER CAPACITANCE	C _{rss}		120		

<u>SENSITRON</u> SEMICONDUCTOR

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MECHANICAL DIMENSIONS: in Inches / mm

TO-254

PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
MOSFET	DRAIN	SOURCE	GATE
TO-254 PACKAGE			



TECHNICAL DATA

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